Control of strong-field ionization in ferroelectric lithium niobate: Role of the spontaneous polarization

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We report the control of tunnel ionization in lithium niobate (LiNbO_3) using phase-controlled two-color laser fields. Through a macroscopic observable of high contrast, we disclose the crucial contribution of the microscopic spontaneous polarization of the ferroelectric material to the ionization rate: as the relative two-color phase is varied, the ablated area of LiNbO_3 is modulated by 35% when the laser and crystal polarization directions are parallel. Rotating the sample by 180° around the laser propagation axis leads to an out-of-phase modulation. We use a two-band model to highlight the key contribution of the material's spontaneous polarization for the symmetry breaking of the ionization rate. Our results open new perspectives for the direct control of ionization dynamics in solids by tailoring the electric field of femtosecond laser pulses.

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I. INTRODUCTION

Strong-field ionization (SFI) of atoms and molecules with intense laser pulses has been widely investigated in the last decades [1–3] and led to an in-depth understanding of several photoinduced ultrafast processes [4]. One of the most striking outcomes is the emergence of attosecond ($1 \text{ as} = 10^{-18} \text{ s}$) science, which now allows tracking electrons on their natural timescale [5]. In semiconductor and dielectric materials, SFI is the primary step for phenomena such as refractive index changes [6], high-harmonic generation [7,8], and in the extreme case, optical breakdown [9] triggering laser-induced ablation (LIA) [10,11]. For both, atoms and solids, Keldysh developed a common theory 55 years ago in which an adiabatic parameter γ is delimiting the perturbative regime ($\gamma > 1$) from the tunneling one ($\gamma < 1$) [3]. While the gas phase is well elucidated, experiments in solids focused mainly on interactions within the perturbative limit. Only a very few studies have explored the tunneling regime [12–16], even though this number is expected to increase rapidly due to the recent availability of low-frequency laser pulses in the infrared (IR) spectral range [17]. Efforts in that direction are of significant importance since various materials with large band gap compared to IR photon energies are promising candidates

for numerous technological applications. For instance, lithium niobate (LiNbO_3) and chalcogenide glasses are notable compounds used in optical switches and IR detectors [18,19].

Many questions remain to be answered to link the well-understood gas phase to the solid state. Of particular interest is the case of noncentrosymmetric systems due to their permanent polarization. It is known that the ionization rate of noncentrosymmetric diatomics in the tunneling regime critically depends on the orientation of the molecular axis relative to the polarization of the laser field [20]. Moreover, strong-field ionization of asymmetric gas molecules typically displays preferential emission directions in molecular frame photoelectron angular distributions (MF-PADs), depending on whether the permanent dipole moment is parallel or antiparallel to the laser field [21]. For crystals, the atomic composition and configuration of the unit cell define their band structure and physical properties. The question naturally arises whether there are similar responses to SFI for noncentrosymmetric gas molecules and materials. Furthermore, can waveform shaping of the laser electric field lead to control over SFI as in the molecular case [22–25]? In this article, we extend the understanding of SFI to the solid state by investigating the interaction between intense femtosecond laser pulses and LiNbO_3 , a synthetic material employed in several devices due to its ferroelectricity and distinctive optical properties [26]. We use the sensitivity of LIA to probe and control SFI in the tunneling regime by measuring the ablated area at the surface of the material as a function of the relative

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FIG. 1. (a) Sketch of the experimental setup. A laser field composed of the superposition of a fundamental frequency ω ($\lambda = 1800$ nm) and its second harmonic 2ω ($\lambda = 900$ nm) is employed to ablate the surface of LiNbO_3 samples just above the threshold fluence. The relative two-color phase ϕ is adjusted by translating a motorized wedge in a direction perpendicular to the laser propagation axis and the beam is focused onto the crystal with an off-axis parabolic mirror. A fast ceramic motor stage ensures single-shot ablation by translating the sample in a direction parallel to its surface. The laser polarization and the c axis of the crystal are oriented vertically. After a first ablation series, the sample is rotated by 180° and the procedure is repeated. (b) Waveform representation of the electric field for $\phi = 0, \frac{\pi}{2}, \pi$ [Eq. (1)]. The direction of the peak field with respect to the c axis of LiNbO_3 changes every $\Delta\phi = \pi$.

phase between a fundamental field (1800 nm) and its second harmonic (900 nm). The experimental results are supported by numerical simulations based on a two-band model, which establish the role of the spontaneous polarization of LiNbO_3 during the photoionization process.

II. EXPERIMENTS

For the experiments presented in Fig. 1(a), the 2.5 kHz (30 fs) Ti:sapphire laser system of the Advanced Laser Light Source (Canada) served as the input for pumping a whitelight seeded optical parametric amplifier (TOPAS, Light Conversion) which delivered the 1800-nm pulses. After spatial filtering, 350 mW (140 μJ) were used for second-harmonic generation (SHG) in a type-1 $\beta\text{-BaB}_2\text{O}_4$ (BBO) crystal ($\Theta = 20^\circ$, $\Phi = 0^\circ$) and both beams were sent to a Mach-Zehnder-like interferometer. Spectral separation of the 1800- and 900-nm beams was achieved by a low-dispersion dichroic beam splitter (LaserOptik). The laser polarization angle and energy were controlled in each interferometer arm using a combination of polarizer and half-waveplate. The fundamental and SH fields were recombined through a second dichroic beam splitter and sent through a pair of wedges to adjust and scan their relative phase ϕ , which was actively stabilized in a similar scheme as in Refs. [27,28]. To avoid chromatic aberrations, the resulting two-color pulses were focused at the surface of 10×10 mm Y-cut LiNbO_3 samples (MTI Corporation, Curie temperature $T_c \simeq 1160^\circ\text{C}$) by a 50-mm focal length off-axis parabolic gold mirror. The surface thickness was 0.5 mm and its roughness below 8 Å. The

FIG. 2. Single-shot ablated area as a function of the relative two-color phase for $\theta = 0^\circ$ (solid blue) and $\theta = 180^\circ$ (dashed orange). Each data point is averaged over ten measurements and the standard deviation is shown.

experiments were performed in air and single-shot ablation craters were created due to a fast translation of the sample in the direction perpendicular to the laser propagation axis (for details on LIA see the Supplemental Material [28], and Refs. [29–33] therein). The beam radius at focus ($1/e^2$ of intensity) for both 1800 and 900 nm fields was $\sim 17 \mu\text{m}$ and their pulse duration was characterized to 65 fs from SHG-frequency-resolved optical gating measurements. The intensities for the 1800- and 900-nm fields were respectively 1.6×10^{13} and $7.7 \times 10^{12} \text{ W cm}^{-2}$. Shot-to-shot energy fluctuations were measured to be 2% at 1800 nm and 3% at 900 nm. The craters were imaged with a Nikon Eclipse microscope (100 $\times$ objective) and their area was determined with a fitting routine whose accuracy was cross-checked by atomic force microscopy measurements [28].

III. RESULTS AND DISCUSSION

A. Two-color LIA measurements

We first address the following question: Can tunnel ionization in a solid be efficiently controlled as has been demonstrated in atomic and molecular gases [22–25,34,35]? To do so, we experimentally used a two-color field expressed by

$$\mathcal{F}(t) = \mathcal{F}_1(t)\cos(\omega t) + \mathcal{F}_2(t)\cos(2\omega t + \phi), \quad (1)$$

where $\mathcal{F}_1$ and $\mathcal{F}_2$ are the envelope functions of the fundamental field and its second harmonic, of frequencies ω and 2ω , respectively. By varying the relative phase ϕ , one can shape the waveform of the total electric field under the envelope and control its polarity [Fig. 1(b)]. We therefore performed two-color LIA with the c axis of the crystal parallel to the laser polarization ($\theta = 0^\circ$). Figure 2 shows the resulting ablated area in LiNbO_3 as a function of ϕ for $\theta = 0^\circ$ (blue solid curve). A clear phase dependence is observed with a periodicity that is half the fundamental period. The modulation amplitude corresponds to 35% of the mean value. From Eq. (1) the peak electric field is maximal when $\phi = 0$ or π , differing solely by its polarity. The successive extrema with a $\Delta\phi = \pi$ in Fig. 2 thus demonstrate that the ablation process is sensitive to the field polarity for a laser polarization parallel

to the crystal c axis. For a process depending on the direction of the peak electric field, one would expect that rotating the sample by 180° with respect to the laser polarization would revert the observed trend regardless of the mechanism. This is confirmed by the orange (dashed) curve, showing an out-of-phase dependence when repeating the measurements for $\theta = 180^\circ$ and preserving the same initial two-color phase [28]. Experimentally, such a control is achieved most efficiently in the vicinity of the fundamental field ablation threshold. For higher intensities, the contribution of avalanche ionization to LIA reduces the sensitivity to SFI, an effect that was also observed in single-color angular LIA measurements [36]. Optimal control is obtained for a 2:1 (1800 nm:900 nm) intensity ratio, while further increasing the SH intensity leads to a loss of modulation. Moreover, the modulation amplitude vanishes completely at $\theta = 90^\circ$.

B. Determination of the spontaneous polarization

In our experiment, the photon energy of 0.69 eV (1800 nm) is well below the 3.78 eV experimental band gap of LiNbO₃ [37,38]. Together with the laser intensity employed in the experiments, this ensures that ionization is due to tunneling ($\gamma = 0.57$). 180° apart from each other, the two studied crystal orientations possess an identical band structure [28]. Therefore, the observed π phase shift between the curves in Fig. 2 suggests a non-negligible contribution from the spontaneous polarization of LiNbO₃, which is known to be particularly high along its c axis. The effect of this spontaneous polarization is comparable to an internal electric field within the material that can either add up to or subtract from the laser electric field. Consequently, the modulation amplitude in the ablated area observed in Fig. 2 is attributable to an effect from a parallel vs antiparallel spontaneous polarization relative to the laser peak electric field. Based on this assumption, we estimate the spontaneous polarization of LiNbO₃ from the regression method that was used to determine the ablation threshold of the material. Figure 3 shows the ablated area of LiNbO₃ with increasing fluence for the 1800-nm field only. Experimentally, the ablation threshold fluence F_{th} can be evaluated according to $A(F) = \pi/2r_0^2 \ln(F/F_{th})$ where A is the ablated area, r_0 the effective beam radius ($1/e^2$), and F the laser fluence [39,40]. From this fitting, we report $F_{th} = 0.51$ J/cm² in lithium niobate at an 1800-nm wavelength.

To retrieve the value of the effective spontaneous polarization of the material, we evaluate the peak electric field difference $\Delta\mathcal{F}$ corresponding to the fluences that would be required to reach maxima (170 μm^2) and minima (120 μm^2) in the two-color measurements, as illustrated in Fig. 3. After considering Fresnel losses of the field $\mathcal{F}$ [41], the resulting field in the material corresponds to $\mathcal{F}_{\text{LiNbO}_3} = 2\mathcal{F}/(n_e + 1)$, with the refractive index $n_e = 2.13$ at 1800 nm. A value of $\Delta\mathcal{F}_{\text{LiNbO}_3} = 0.46$ GV/m is obtained for which the half-value corresponds to a spontaneous polarization $|P_s| = 0.06$ C/m² ($\epsilon = 2.54 \times 10^{-10}$ F/m) [26]. Although there is no precise technique to characterize this property, $|P_s|$ in LiNbO₃ has been reported to range between 0.6 and 0.8 C/m² from density-functional theory calculations and polarization switching measurements [42–44]. In most cases, a pure stoichiometric crystal is considered and the reported values thus correspond to an upper

FIG. 3. Determination of the spontaneous polarization. The ablated area as a function of 1800-nm field fluence (logarithmic scale) is shown. An ablation threshold of 0.51 J/cm² is retrieved from the fit. Dashed lines show the interpolated fluences for the maximal and minimal crater area in Fig. 2 from which a spontaneous polarization of 0.06 C/m² is retrieved.

limit. The reduced value retrieved in our experiments may be attributed to the initial presence of free charges within the material due to defects, intrinsically present for non-stoichiometric LiNbO₃ samples. Screening by free carriers, together with surface charge density effects [45], are expected to reduce significantly the effective spontaneous polarization.

C. Two-band model

To get deeper insight into the underlying control mechanism, we used the experimentally retrieved P_s to simulate the two-color phase dependence of the ionization process with a two-band model for LiNbO₃. The calculations are performed by solving the semiconductor Bloch equations (for theoretical details, see the Supplemental Material [28] and references [46–50] therein). In presence of the laser field, the band gap E_g undergoes an AC Stark shift that is described to the first order by

$$E_g(\mathcal{F}) = E_g(0) - \mu\mathcal{F}(t)_{\text{LiNbO}_3}, \quad (2)$$

where $E_g(0)$ is the field-free band-gap energy and $\mathcal{F}(t)_{\text{LiNbO}_3}$ is the two-color laser electric field in the material. This is in direct analogy to Stark shifts experienced by asymmetric molecules in intense laser fields [51]. The permanent dipole of LiNbO₃ along its c axis, μ , is obtained by multiplying P_s by the volume of the unit cell [28]. The retrieved $P_s = \pm 0.06$ C/m² thus enters Eq. (2) via the permanent dipole μ and the dynamical band-gap energy is included in our two-band model. Figure 4 shows the resulting conduction band population of the material as a function of ϕ . The two spontaneous polarizations $P_s = \pm 0.05$ C/m² and $P_s = \pm 0.1$ C/m²

FIG. 4. Two-band model calculations. The conduction band (CB) population as a function of the relative two-color phase ϕ is shown for $\theta = 0^\circ$ and $\theta = 180^\circ$. The two orientations correspond to a sign reversal of the spontaneous polarization that is either parallel or antiparallel to the laser peak electric field. Different values are compared: $P_s = \pm 0.05$ C/m² (green squares and purple line), $P_s = \pm 0.1$ C/m² (blue circles and orange crosses), and $P_s = 0$ C/m² (black dots). While a sign reversal leads to a π phase shift of the modulation, the frequency is doubled when $P_s = 0$ C/m² (black dots, right scale).

are compared. A sign reversal is equivalent to rotating the sample spatially from $\theta = 0^\circ$ to 180° .

First, one can observe by comparing $P_s = +0.05$ and -0.05 C/m² (green squares and purple line) that reversing P_s leads to a π -shifted modulation. Increasing to $P_s = +0.1$ and -0.1 C/m² (blue circles and orange crosses), this feature is preserved and the modulation amplitude is enhanced. As described by Eq. (2), a larger spontaneous polarization ($|P_s| = 0.05$ vs 0.1 C/m²) amplifies the AC Stark effect on the band-gap energy [28]. Since the ionization rate depends exponentially on E_g , this leads to a significant increase of the modulation amplitude of the conduction band population. In agreement with the experimental results of Fig. 2, extrema arise every $\Delta\phi = \pi$, confirming the dependence of the ionization process on the electric field polarity. For comparison, the black curve describes ionization when the spontaneous polarization of LiNbO₃ is not taken into account ($P_s = 0$). In this case, the modulation frequency is doubled and the process depends on $|\mathcal{F}|^2$, confirming the key role of the spontaneous polarization as the precursor for the symmetry breaking. The transition from $P_s = 0$ to 0.1 C/m² in the two-color phase dependence illustrates the change of periodicity induced by the material [28]. It can be noted that in the simulations (Fig. 4) an extrema is observed precisely at $\phi = 0$, in agreement with Eq. (1). This is not observed in the experimental results (Fig. 2) because for this latter case the initial two-color phase ϕ is unknown but arbitrarily chosen as a relative zero. While our simulations provide a

qualitative interpretation, additional effects should be taken into account for a quantitative modeling. For instance, indirect band-gap transitions in the tunneling regime may contribute to the conduction band population. Thermodynamic properties such as electron and ion temperatures and pressures should also be considered [11].

IV. CONCLUSION

In summary, we demonstrated an efficient control of the tunnel ionization rate in lithium niobate from LIA measurements. By using a phase-controlled two-color laser field to ablate the ferroelectric material, we observed modulations as high as 35% in the ablated area when varying the relative phase between an 1800-nm field and its second harmonic. The results are explained by a two-band model, which clarifies the control mechanism as a consequence of the spontaneous polarization in LiNbO₃. This is in close analogy to the molecular case, where, however, noncentrosymmetric molecules must be oriented in the laboratory frame in order to determine the influence of permanent dipole moment and polarizability [21]. From a regression method, we evaluated $|P_s|$ to be 0.06 C/m². Simulations show that parallel and antiparallel spontaneous polarization relative to the laser peak electric field direction influences the AC Stark shift of the band-gap energy. This, in turn, impacts on the ionization rate of the material and leads to ablated craters of different sizes. Our experimental approach hence allows interpreting the role of the spontaneous polarization in the ionization of ferroelectric materials. Smaller band-gap materials with high P_s should lead to enhanced control. This will, however, require mid-infrared wavelength pulses with microjoules of energy to remain in the tunneling regime. The observed phase sensitivity of femtosecond laser-induced ablation can find applications in laser micromachining but most importantly it opens a route for the direct control of ionization dynamics within crystals through femtosecond pulse shaping. For example, our results offer new degrees of freedom for high-order harmonic generation from solids, a promising candidate for the design of compact extreme ultraviolet sources. Finally, the findings also suggest a potential phase meter scheme, exploiting solid samples, to identify the carrier-envelope phase of few-cycle laser pulses covering the mid- and far-IR spectral ranges gaining in accessibility in many laboratories.

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